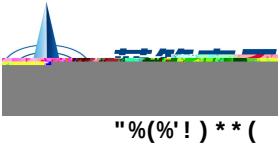


' , ' - . / 0 - 1 ' 2 - 3 4 2 1 ' '

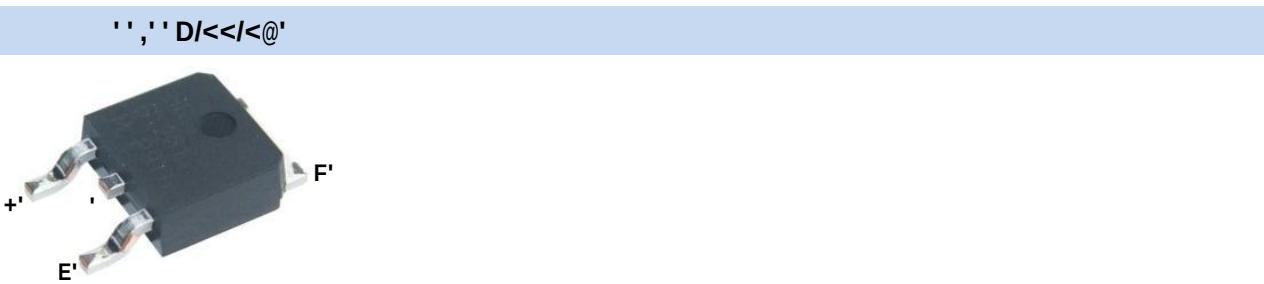
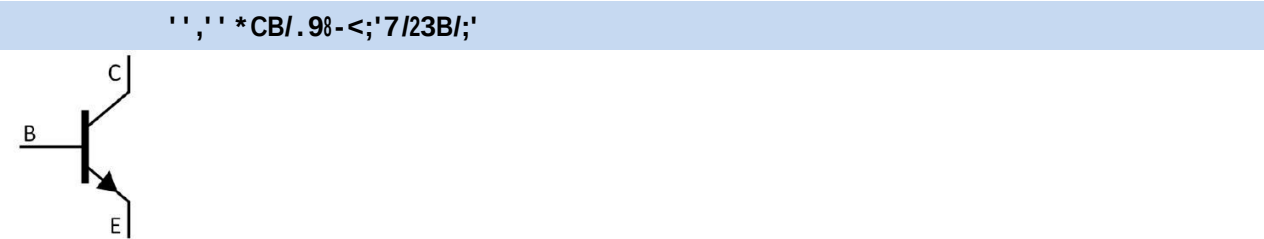
E	2016-5				
F	2021-4-20	1			
A	2022-4-23	all	BR Q TO-252 TO-252#, AEC-Q101 Q 245±5°C 5 ±0.5sec 255 ±5°C 5±0.5sec		



' , ' " -032/A;/4<0'
TO-252 NPN ! " # \$ % & ' Silicon NPN transistor in a TO-252 Plastic Package.

' , ' ' 6-9;B2-0'
(BR2SB649ADQ) * + , - AEC-Q101 . / 0 1 2 3 4 5 + 6 7 8 9 '
Complementary pair with BR2SB649ADQ, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

' , ' ' %AA8/39;/4<0'
: ; < = > ? @ A + B C D E F : G H I 4 5 '
Low frequency power amplifier, Meet the stringent requirements of automotive applications.



PIN1 J Base PIN 2,4 J Collector PIN 3 J Emitter

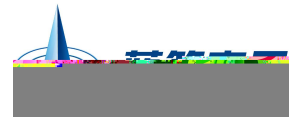
Table with 4 columns: hFE Classifications Symbol, B, C, D. Row 1: hFE Range, 60~120, 100~200, 160~320.

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	180	V
Collector to Emitter Voltage	V_{CEO}	160	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.5	A
Collector Current – Continuous(Pulse)	I_{CP}	3.0	A
Collector Power Dissipation	P_C	1.0	W
Collector Power Dissipation	$P_C(T_c=25^{\circ}C)$	10	W
Junction Temperature	T_j	150	$^{\circ}C$
Storage Temperature Range	T_{stg}	-55~150	$^{\circ}C$

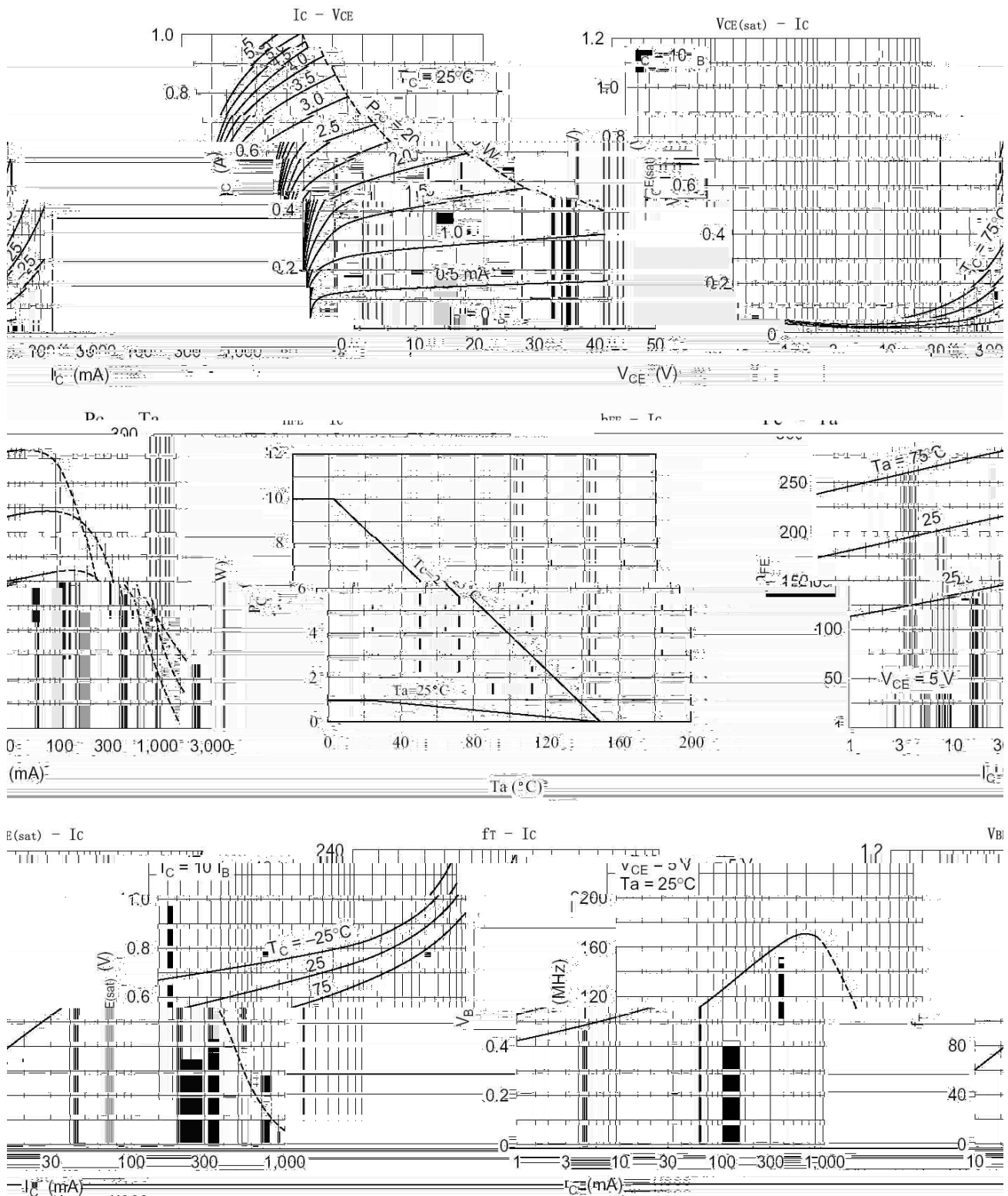
FE(

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=1.0mA$ ' $I_E=0$	180	'		V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=10mA$ ' $R_{BE}=\infty$	160			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=1.0mA$ ' $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=160V$ ' $I_E=0$			10	μA

DC Current Gain $h_{FE(1)}$ $V_{CE}=5.0V$ 2 $I_C=150mA$ 60 320



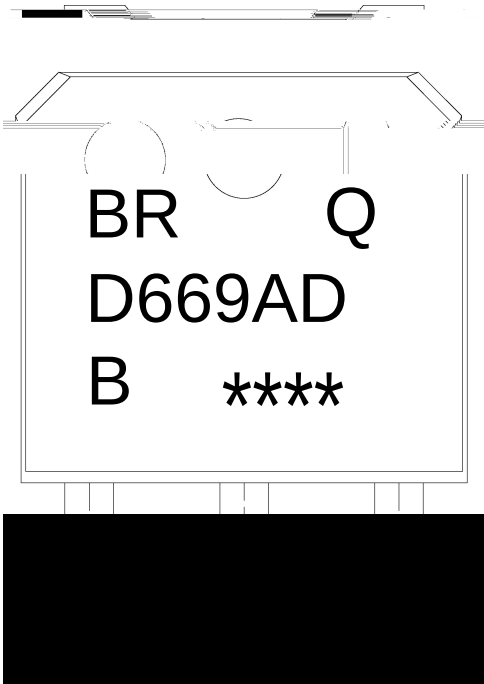
'', '' *8-3;2/398'7 59293;-2/0;/3'7 B2. -'



! "##\$%"&'

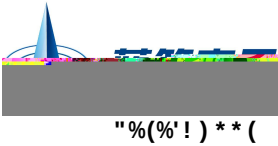
Rev.A Apr.-2022

' ' , ' ' > 92? / < @ ' % < 0 ; 2 B 3 ; / 4 < 0 '

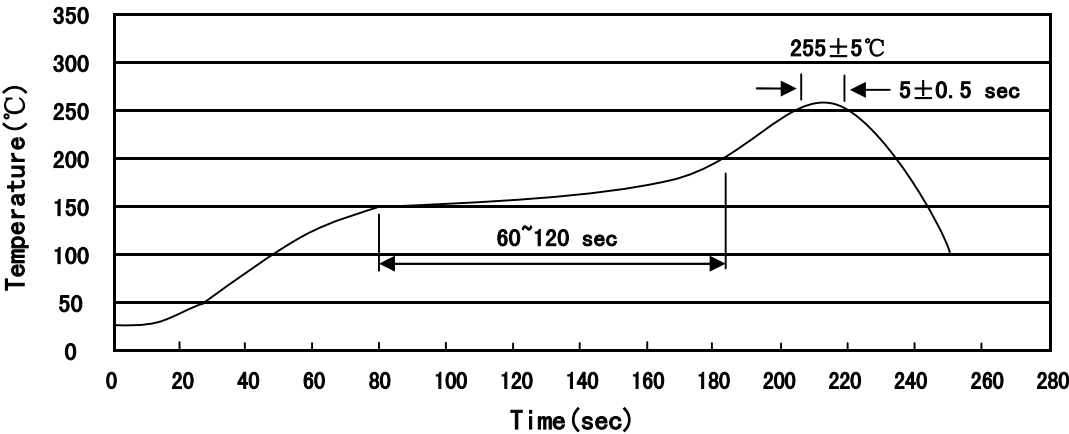


BR
Q
D669AD
B: h_{FE}

Note:
BR: Company Code
Q: Automobile halogen-free product Code
D669AD: Product Type
B: h_{FE} Classifications Symbol
****: Lot No. Code, code change with Lot No



J ''' , ' ' Temperature Profile for IR Reflow Soldering(Pb-Free)'



Note:

- 1 150 200 60 120sec; 1.Preheating:150~200°C, Time:60~120sec.
- 2 255±5 5±0.5sec; 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
- 3 2 10°C/sec. 3. Cooling Speed: 2~10°C/sec.

'' , ' ' -0/0;9<3-';4' ! 481-2/<@') -9;' (-0;'74<1/;/4<0'

260±5°C 10±1 sec. Temp.:260±5°C Time:10±1 sec

'' , ' ' D93?9@/ <@' ! D* 70'

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box 盒	Outer Box 箱
TO-252	2,500	2	5,000	6	30,000	13" ×16	360×360×50	380×335×366

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube 套管	Inner Box 盒	Outer Box 箱
TO-251/252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

'' , ' ' P4;/3-0